

**AMENDMENTS TO THE CLAIMS**

1-27. (Cancelled)

28. (Currently Amended) A sequential lateral solidification (SLS) mask comprising:

a light absorptive portion for blocking a laser beam; and

a plurality of stripe-shaped light transmitting portions for passing the laser beam, wherein at least one end of each light transmitting portion has a shape of one of triangle and semicircle and a width of said at least one end is smaller than a width of a central point of the light transmitting portion ~~the plurality of stripe-shaped light transmitting portions have a shape such that an intensity of the laser beam passing through at least one end is substantially lower than an intensity of the laser beam passing through other portions due to interference and scattering of the laser beam.~~

29. (Currently Amended) The mask of claim 28, wherein both ends of each light-transmitting portion have the shape of triangle ~~includes triangular-shaped edges on both sides.~~

30. (Currently Amended) The mask of claim 28, wherein both ends of each light-transmitting portion have the shape of semicircle ~~includes semicircular-shaped edges on both sides.~~

31. (Currently Amended) The mask of claim 28, wherein the distance between the adjacent light transmitting portions is less than or equal to the width of the central point of the light transmitting portion.

32. (Currently Amended) The mask of claim 28, wherein the width of the central point of the light transmitting portions is less than or equal to twice the maximum length of lateral grain growth that is to be grown by sequential lateral solidification (SLS).

33. (New) A sequential lateral solidification (SLS) mask for crystallizing amorphous silicon, the SLS mask comprising a light absorptive portion for blocking a laser beam; and a stripe-shaped light transmitting portion having an end with a taper for passing the laser beam.